Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low V_F = 0.33 V at I_F = 5.0 A

TMBS® TO-263AB K (1) 2 1 VBT2045C PIN 1 0 (1) K

HEATSINK

PRIMARY CHARACTERISTICS				
Package TO-263AB				
I _{F(AV)}	2 x 10 A			
V _{RRM}	45 V			
I _{FSM}	160 A			
V_F at $I_F = 10$ A	0.41 V			
T _J max.	150 °C			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 245 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT2045C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	٨	
	per diode		10	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	160	А	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C	

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RoHS COMPLIANT HALOGEN





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	— T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V	
	I _F = 10 A			0.49	0.58		
	I _F = 5 A	T _A = 125 °C		0.33	-		
	I _F = 10 A			0.41	0.52		
Reverse current per diode	$V_{R} = 45 V \qquad \frac{T_{A} = 25 °C}{T_{A} = 125 °C}$	T _A = 25 °C	I _R (2)	-	2000	μA	
		'R (=/	10	30	mA		

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT2045C	UNIT	
Typical thermal resistance	per diode	R _{θJC}	3.0	- °C/W	
	per device		2.0		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT2045C-M3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT2045C-M3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

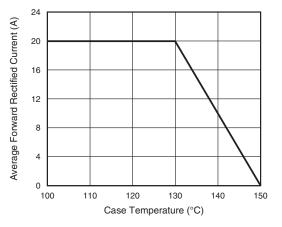


Fig. 1 - Maximum Forward Current Derating Curve

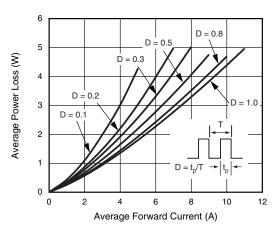


Fig. 2 - Forward Power Loss Characteristics Per Diode

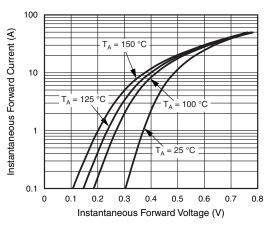
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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

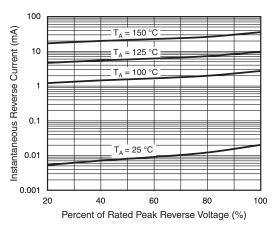
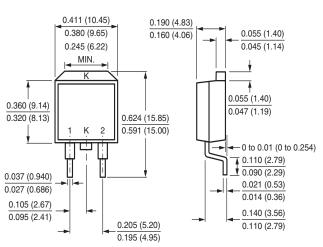


Fig. 4 - Typical Reverse Characteristics Per Diode





TO-263AB

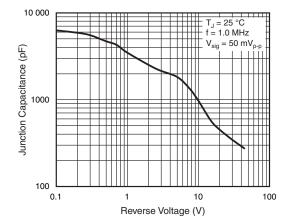


Fig. 5 - Typical Junction Capacitance Per Diode

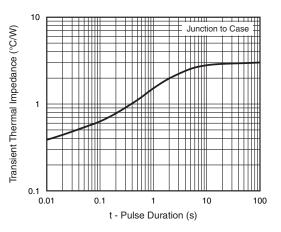
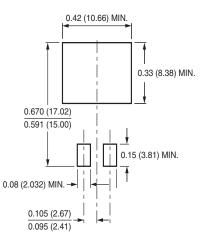


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Mounting Pad Layout



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